

STP12IE90F4

Emitter Switched Bipolar Transistor ESBT $^{\tiny{(8)}}$ 900 V - 12 A - 0.083 Ω

General features

V _{CS(ON)}	Ic	R _{CS(ON)}
1V	12A	0.083 Ω

- High voltage / high current Cascode configuration
- Low equivalent on resistance
- Very fast-switch up to 150 kHz
- Squared RBSOA up to 900V
- Very low C_{iss} driven by $R_G = 47\Omega$
- Very low turn-off cross over time

Applications

- Flyback SMPS for adapter
- Flyback / forward SMPS for desktop

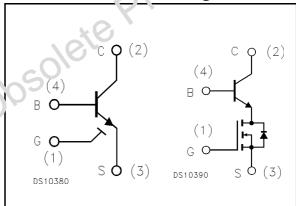
Description

The STP12IE90F4 is manufactured in Monolithic ESBT Technology, aimed to provide best performances in high frequency / high voltage applications.

It is designed for use in Gate Driver, based topologies.



Internal schematic diagrams

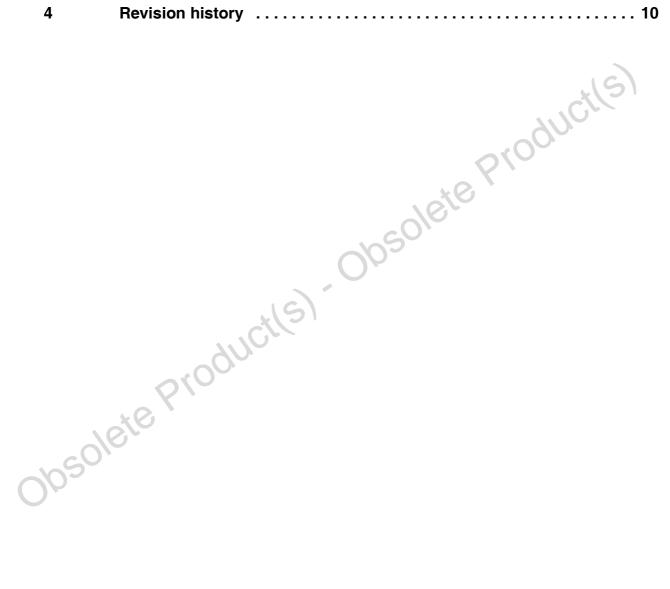


Crder codes

Part Number	Marking	Package	Packing
STP12IE90F4	P12IE90F4	TO220FP-4L	Tube

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STP12IE90F4 Electrical ratings

1 Electrical ratings

Table 1. Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CS(SS)}	Collector-source voltage (V _{BS} = V _{GS} = 0 V)	900	V
V _{BS(OS)}	Base-source voltage (I _C = 0, V _{GS} = 0 V)	30	V
V _{SB(OS)}	Source-base voltage (I _C = 0, V _{GS} = 0 V)	17	V
V _{GS}	Gate-source voltage	土 17	V
I _C	Collector current	12	Α
I _{CM}	Collector peak current (t _P < 5ms)	36	Α
I _B	Base current	6	Α
I _{BM}	Base peak current (t _P < 5ms)	10	А
P _{tot}	Total dissipation at T _c = 25°C	21	W
T _{stg}	Storage temperature	-40 to 150	°C
TJ	Max. operating junction temperature	150	ç

Table 2. Thermal data

	Symbol	Parameter		Value	Unit
	R _{thj-case}	Thermal resistance junction-case	max	6	°C/W
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Electrical characteristics STP12IE90F4

2 Electrical characteristics

 $(T_{case} = 25^{\circ}C \text{ unless otherwise specified})$

Table 3. Electrical characteristics

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CS(SS)}	Collector-source current (V _{BS} = V _{GS} = 0)	V _{CE} = 900V			100	μА
I _{BS(OS)}	Base-source current (I _C = 0, V _{GS} = 0)	V _{BS(OS)} = 30V			10	μΑ
I _{SB(OS)}	Source-base current (I _C = 0, V _{GS} = 0)	V _{SB(OS)} = 17V			100	μА
I _{GS(OS)}	Gate-source leakage	V _{GS} = ± 17V			100	nA
V _{CS(ON)}	Collector-source ON voltage	$V_{GS} = 10V$ $I_C = 12A$ $I_B = 2.4A$ $V_{GS} = 10V$ $I_C = 6A$ $I_B = 0.6A$		1 0.6	1/3	V V
h _{FE}	DC current gain	$V_{GS} = 10V I_C = 12A V_{CS} = 1V$ $V_{GS} = 10V I_C = 6A V_{CS} = 1V$	OG	5 15		
V _{BS(ON)}	Base Source ON voltage	$V_{GS} = 10V I_C = 12A I_B = 2.4A$ $V_{GS} = 10V I_C = 6A I_B = 0.6A$		1.5 1.2		V V
V _{GS(th)}	Gate threshold voltage	$V_{BS} = V_{GS}$ $I_B = 250 \mu A$	2	3	4	٧
C _{iss}	Input capacitance	$V_{CS} = 25V$ $f = 1MHz$ $V_{GS} = 0V$		520		pF
Q _{GS(tot)}	Gate-source Charge	V _{CS} =25V V _{GS} =10V V _{CB} =0V I _C =4A		21.3		nC
t _s	INDUCTIVE LOAD Storage time Fall time	V_{GS} =10V R_{G} =47 Ω V_{Clamp} =720V t_{p} =4 μ s I_{C} =6A I_{B} =1.2A		610 10		ns ns
t _s	INDUCTIVE LOAD Storage time Fall time	V_{GS} =10V R_{G} =47 Ω V_{Clamp} =720V t_{p} =4 μ s I_{C} =6A I_{B} =0.6A		360 10		ns ns
v _{CSW}	Maximum collector- source voltage switched without snubber	$R_G = 47\Omega$ $h_{FE} = 5$ $I_C = 12A$	900			٧

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _{CS(dyn)}	Collector-source dynamic voltage (500ns)	$\begin{aligned} &V_{CC} = &V_{Clamp} = &400 V \\ &V_{GS} = &10 V &I_{C} = &6 A \\ &I_{B} = &1.2 A &t_{peak} = &500 ns \\ &R_{G} = &47 \Omega &I_{Bpeak} = &6 A \left(I_{C} \right) \end{aligned}$		3.37		V
V _{CS(dyn)}	Collector-source dynamic voltage (1µs)	$\begin{aligned} &V_{CC} = &V_{Clamp} = &400V \\ &V_{GS} = &10V & I_{C} = &6A \\ &I_{B} = &1.2A & t_{peak} = &500ns \\ &R_{G} = &47\Omega & I_{Bpeak} = &6A \left(I_{C}\right) \end{aligned}$		1.75		٧

Figure 2.

Table 3. Electrical characteristics

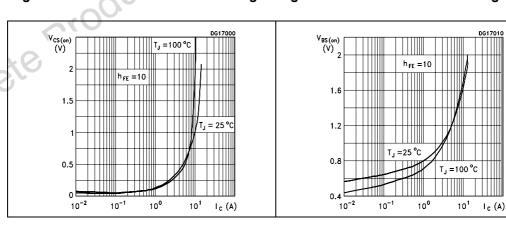
2.1 Electrical characteristics (curves)

Figure 1. DC current gain

Collector-source On voltage

 h_{FE} $T_{J} = 100 \, ^{\circ}\text{C}$ $T_{J} = 25 \, ^{\circ}\text{C}$ $V_{CS} = 1V$ 10^{0} 10^{-2} 10^{-1} 10^{0} 10^{1} 10^{1} 10^{1} 10^{1} 10^{1} 10^{1} 10^{1} 10^{1} 10^{1} 10^{1} 10^{1} 10^{1} 10^{1} 10^{1} 10^{1}

Figure 3. Collector-source On voltage Figure 4. Base-source On voltage



Electrical characteristics STP12IE90F4

Figure 5. Reverse biased SOA

Figure 6. Dynamic collector-emitter voltage

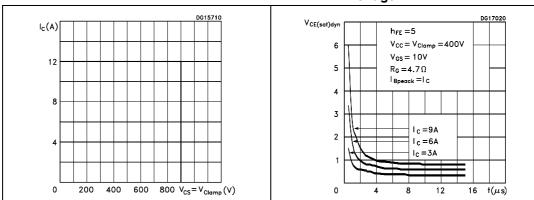
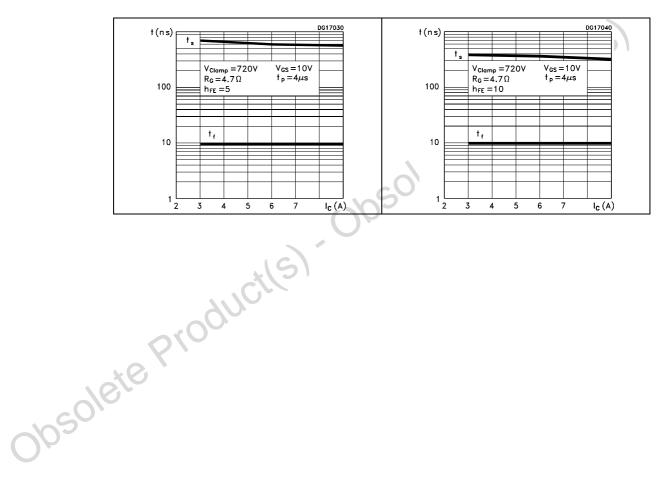


Figure 7. Inductive load switching time Figure 8. Inductive load switching time



2.2 Test circuits

Figure 9. Static V_{CS(ON)} test circuits

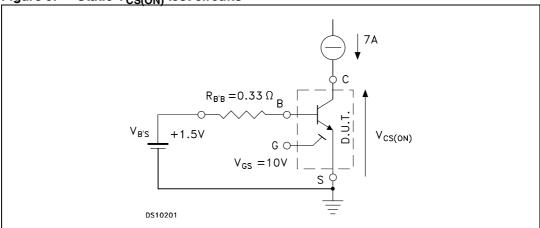
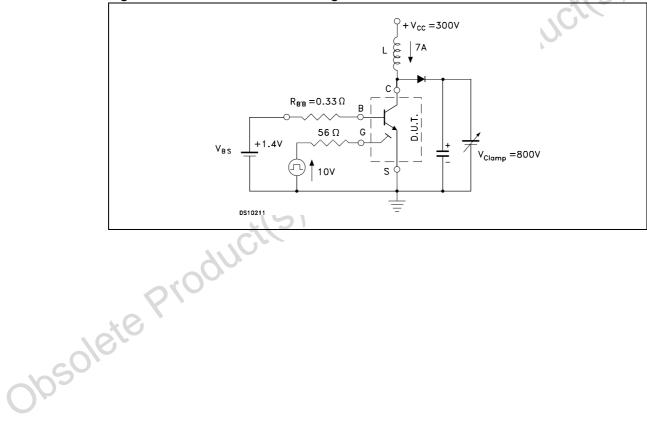


Figure 10. Inductive load switching and RBSOA test circuit



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3 Package mechanical data

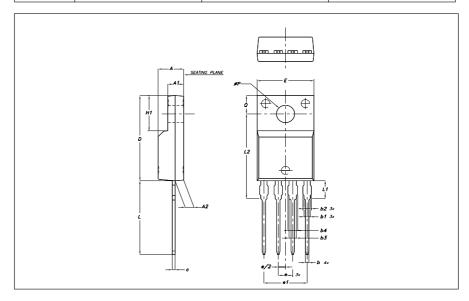
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Obsolete Product(s). Obsolete Product(s)

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TO220FP-4L MECHANICAL DATA

DIM.		mm.	
DIW.	MIN.	TYP	MAX.
A	4.30		4.70
A1	2.60		3
A2	1.30	1.50	1.70
b	0.50		0.70
b1	1.05		
b2			1.30
b3	1.25		
b4			1.50
С	0.45	0.50	0.60
D	15.50		15.90
E	9.80		10.20
е	2.29	2.54	2.79
e1		7.62	
H1	6.30		6.70
L		13.60	
L1		3.30	
L2	15.40		15.80
Dia P	3		3.40
Q	3.30		3.50



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Revision history STP12IE90F4

4 Revision history

Table 4. Revision history

Date	Revision	Changes
28-Jul-2006	1	Initial release.
16-Jan-2007	2	New graphics

Obsolete Product(s). Obsolete Product(s)

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